

GaAs MMIC 6-bit Digitally Controlled Phase Shifter Chip, 13-15GHz

Performance characteristics

Frequency Range: 13 - 15 GHzInsertion loss: 8.3dB (Typ.)

• Amplitude change in each state: 2.0 dB

Phase shift accuracy (RMS): 1.2 °

50Ohm input / output100% on-wafer testing

• Chip size 3.23 x 1.5 x 0.1mm

Product Introduction

GPS-1315-6D is a GaAs MMIC 6-bit digitally controlled phase shifter chip with a frequency range of 13 GHz to 15 GHz, an insertion loss of 8.3 dB, a phase shift accuracy of 1.2°, a change in amplitude of 2.0 dB in each state, and a standing wave of 1.3. The chip uses 0/-5V logic control. The chip uses on-chip through-hole metallization technology to ensure good grounding, does not require additional grounding measures, and is simple and convenient to use. The back of the chip is metallized and is suitable for eutectic sintering or conductive adhesive bonding processes.

Use restriction parameter ¹				
Maximum input power	+23dBm			
Control voltage range	-8V ∼ +0.5V			
Operating temperature	-55 ~ +85°C			
Storage temperature	-65 ~ +150°C			

[1] Exceeding any of these maximum limits may cause permanent damage.

Electrical performance parameters (TA = +25°C)						
Index	Minimum	Typical Value	Maximum	Unit		
Frequency Range		GHz				
Insertion loss		8.3	8.6	dB		
Phase shift accuracy		1.2		dograe		
(RMS)		1.2		degree		
Amplitude changes		2.0		dB		
of each state		2.0		ив		
Input return loss	12	23	-	dB		
Output return loss	10	17	-	dB		
Switching time		20		ns		

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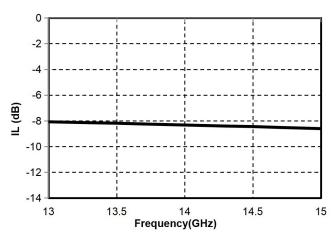
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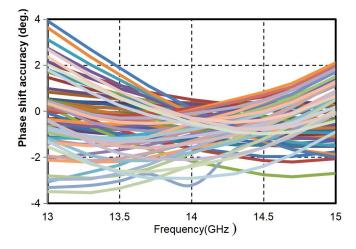
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Main index test curve

Insertion Loss vs. Operating Frequency

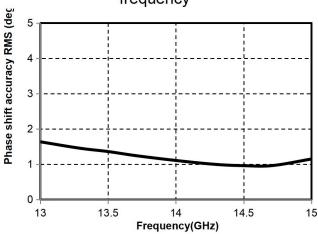


Phase shift accuracy (absolute value) vs. operating frequency

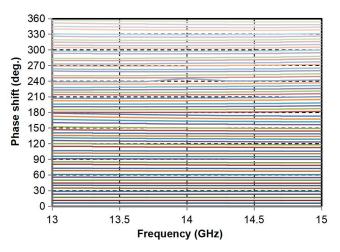


Full-state phase shift input return loss vs. operating frequency

Phase shift accuracy (RMS) vs. operating frequency



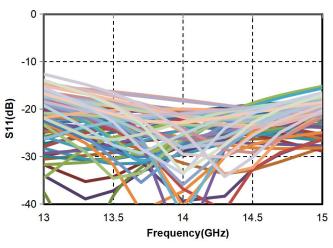
Phase shift vs. operating frequency

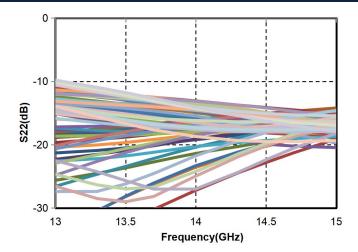


Full-state phase shift output return loss vs. operating frequency

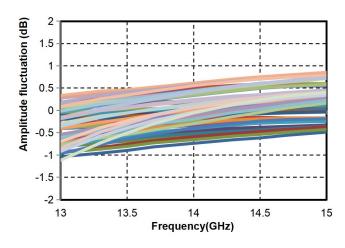




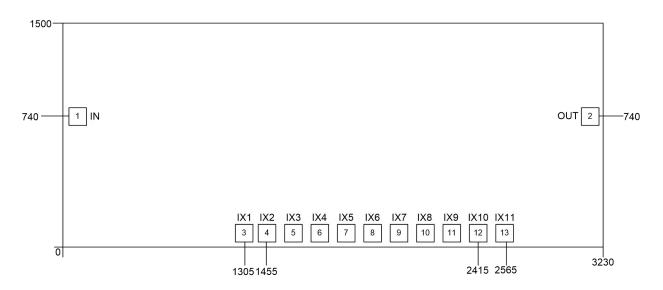




Amplitude changes of each state



Appearance structure ²



[2] All units in the figure are micrometers

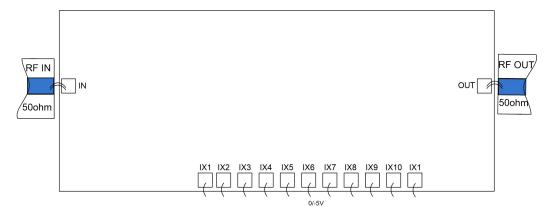


Bonding point definition				
Bonding point	Function	Functional Description		
number	Symbol			
1	RF IN	RF signal input terminal		
2	RF OUT	RF signal output terminal		
3~13	CTRL	Control Port		
Chip bottom	GND	The bottom of the chip needs to be well grounded to RF and DC		

Truth Table

Phase	IX1	IX2	IX3	IX4	IX5	IX6	IX7	IX8	IX9	IX10	IX11
0 state	0	-5	-5	0	-5	-5	0	-5	0	0	-5
5.625	0	-5	0	0	-5	-5	0	-5	0	0	-5
11.25	0	-5	-5	0	-5	0	-5	-5	0	0	-5
22.5	0	-5	-5	0	-5	-5	0	0	-5	0	-5
45	0	-5	-5	0	-5	-5	0	-5	0	-5	0
90	0	-5	-5	-5	0	-5	0	-5	0	0	-5
180	-5	0	-5	0	-5	-5	0	-5	0	0	-5
354.375	-5	0	0	-5	0	0	-5	0	-5	-5	0

Recommended assembly drawing



Precautions for use

- The chip needs to be stored in an anti-static container and kept in a nitrogen environment.
- bare die surface using wet chemical methods .
- Please strictly comply with ESD protection requirements to avoid electrostatic damage to bare chips.
- General operation: Please use precision pointed tweezers to pick up bare chips. Avoid touching the chip surface with tools or fingers during operation.
- Rack mounting operation suggestions: Bare chip mounting can be done by AuSn solder eutectic sintering

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GPS-1315-6D

or conductive adhesive bonding. The mounting surface must be clean and flat.

- Sintering process: It is recommended to use AuSn solder sheets with a gold -tin ratio of 80/20 . The working surface temperature reaches 255 °C and the tool (vacuum chuck) temperature reaches 265 °C. When the high-temperature mixed gas (nitrogen-hydrogen ratio of 90/10) is blown to the chip, the temperature at the top of the tool should be raised to 290 °C. Do not let the chip exceed 320 °C for more than 20 seconds. The friction time should not exceed 3 seconds.
- Bonding process: The amount of conductive glue dispensed should be as small as possible. After the
 chip is placed in the installation position, the conductive glue should be vaguely visible around it. For
 curing conditions, please follow the information provided by the conductive glue manufacturer.
- Bonding operation suggestions: Use Φ0.025mm (1mil) gold wire for both ball and wedge bonding. Thermo-ultrasonic bonding temperature is 150 °C. The pressure of the wedge for ball bonding is 40~50gf, and the pressure of the wedge bonding is 18~22gf. Use the smallest possible ultrasonic energy. The bonding starts at the pressure point on the chip and ends at the package (or substrate).

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